

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|--|-----------------|----------------------|-------------------------|------------------|
| 10/726,678 | 12/04/2003 | Hideshi Miyajima | 04329.3192 | 5698 |
| 22852 | 7590 12/28/2005 | | EXAMINER | |
| FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER | | | UMEZ ERONINI, LYNETTE T | |
| LLP 901 NEW Y | ORK AVENUE, NW | | ART UNIT | PAPER NUMBER |
| WASHINGTON, DC 20001-4413 | | | 1765 | |
| | | | DATE MAILED: 12/28/200 | 5 |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | | υ | | | |
|--|---|--|----|--|--|--|
| | Application No. | Applicant(s) | | | | |
| | 10/726,678 | MIYAJIMA ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Lynette T. Umez-Eronini | 1765 | | | | |
| The MAILING DATE of this communication app Period for Reply | ears on the cover sheet with the c | orrespondence address | | | | |
| A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period v - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). | ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE | N. nely filed the mailing date of this communication. D (35 U.S.C. § 133). | | | | |
| Status | | | | | | |
| 1) Responsive to communication(s) filed on 04 Do | ecember 2003. | | | | | |
| · · · · · · · · · · · · · · · · · · · | action is non-final. | | | | | |
| 3) Since this application is in condition for allowar | nce except for formal matters, pro | secution as to the merits is | • | | | |
| closed in accordance with the practice under E | x parte Quayle, 1935 C.D. 11, 45 | 53 O.G. 213. | | | | |
| Disposition of Claims | | , | | | | |
| 4)⊠ Claim(s) <u>1-20</u> is/are pending in the application. | | | | | | |
| | 4a) Of the above claim(s) is/are withdrawn from consideration. | | | | | |
| 5) Claim(s) is/are allowed. | | | | | | |
| 6)⊠ Claim(s) <u>1-20</u> is/are rejected. | ☑ Claim(s) <u>1-20</u> is/are rejected. | | | | | |
| 7) Claim(s) is/are objected to. | | | | | | |
| 8) Claim(s) are subject to restriction and/or | r election requirement. | | | | | |
| Application Papers | | | | | | |
| 9) The specification is objected to by the Examine | r. | | | | | |
| 10) ☐ The drawing(s) filed on <u>12/4/2003</u> is/are: a) ☐ | accepted or b) objected to by t | he Examiner. | | | | |
| Applicant may not request that any objection to the | drawing(s) be held in abeyance. See | ∋ 37 CFR 1.85(a). | | | | |
| Replacement drawing sheet(s) including the correct | ion is required if the drawing(s) is obj | jected to. See 37 CFR 1.121(d) |). | | | |
| 11)☐ The oath or declaration is objected to by the Ex | aminer. Note the attached Office | Action or form PTO-152. | | | | |
| Priority under 35 U.S.C. § 119 | | | | | | |
| 12)⊠ Acknowledgment is made of a claim for foreign | priority under 35 U.S.C. § 119(a) |)-(d) or (f). | | | | |
| a)⊠ All b) Some * c) None of: | | | | | | |
| Certified copies of the priority documents | 1. Certified copies of the priority documents have been received. | | | | | |
| Certified copies of the priority documents | 2. Certified copies of the priority documents have been received in Application No | | | | | |
| Copies of the certified copies of the prior | • | ed in this National Stage | | | | |
| application from the International Bureau | | | | | | |
| * See the attached detailed Office action for a list | of the certified copies not receive | d. | | | | |
| | | | | | | |
| | | | | | | |
| Attachment(s) | | | | | | |
| 1) Notice of References Cited (PTO-892) | 4) Interview Summary | | | | | |
| 2) | Paper No(s)/Mail Da 5) Notice of Informal Pa | ate atent Application (PTO-152) | | | | |
| Paper No(s)/Mail Date <u>4/30/2004</u> . | 6) Other: | FF | | | | |

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-11; 12-16; and 17-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Loboda (US PGPUB 20020137323 A1) in view of Sato (US 6,306,765 B1).

As to claims 1-20, Loboda teaches, "The barrier (4) may be a $Si_wC_xO_yH_x$ (same as applicants' second insulating film including silicon, carbon, oxygen, and hydrogen) film or a combination of the $Si_wC_xO_yH_x$ film with one or more materials such as SiC:H, as SiN:H, a-SiCN:H (same as applicants' first insulating film including silicon, carbon, nitrogen, and hydrogen), . . . and other known barrier materials" . . . (same as second insulating film including Si, C, N, and H) and $Si_wC_xO_yH_x$ Preferably layer 4 is produced by plasma enhanced chemical vapor deposition . . ." [0027] and by using trimethylsilane, He, N_2O , CO_2 , and N_2 [0037, 0039, 0041-0047].

Loboda differs in failing to teach forming a first and a second insulating film in different chambers, in claims 1 and 5;

irradiating energy ray on the first insulating film, in claim 12; and heating the substrate at the time of irradiating the energy ray on the first insulating film in claim 14 and 17.

Sato teaches filming formation on a substrate by carrying out a chemical vapor deposition in different chambers (claim 16) by flowing reactant and excitation gases in a plasma chamber and applying an RF bias (same as applicants' energy ray), (column 3, lines 32-60).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to use Sato's method of film formation for the purpose of forming films having improved barrier property against the substrate (Sato, column 2, lines 47-53).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lynette T. Umez-Eronini whose telephone number is 571-272-1470. The examiner is normally unavailable on the First Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571-272-1465. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 10/726,678

Art Unit: 1765

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Art Unit 1765

ltue

December 20, 2005

SHAMIMIAHMED PRIMARY EXAMINER Page 4